



Atty. Dkt. No. 039153-0256 (F0113)

AF
2812

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yu
Title: A PROCESS FOR
MANUFACTURING
TRANSISTORS HAVING
SILICON/GERMANIUM CHANNEL
REGIONS
Appl. No.: 09/599,141
Filing Date: 06/22/2000
Examiner: Roman, A.
Art Unit: 2812

CERTIFICATE OF MAILING	
I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to the Commissioner for Patents, Washington, D.C. 20231.	
Joseph N Ziebert	(Printed Name)
<i>[Signature]</i>	(Signature)
12-24-02	(Date of Deposit)

AMENDMENT TRANSMITTAL

Commissioner for Patents
Box AF
Washington, D.C. 20231

Sir:

Transmitted herewith is an amendment in the above-identified application.

- [] Small Entity status under 37 C.F.R. § 1.9 and § 1.27 has been established by a Small Entity statement previously submitted.
- [] Small Entity statement is enclosed.
- [X] The fee required for additional claims is calculated below:

	Claims as Amended	Previously Paid For	Extra Claims Present	Rate	Additional Claims Fee
Total Claims:	26	26	0	\$18.00	\$0.00
Independents:	4	4	0	\$84.00	\$0.00
First presentation of any Multiple Dependent Claims:				\$280.00	\$0.00
CLAIMS FEE TOTAL:					\$0.00

- [] Applicant hereby petitions for an extension of time under 37 C.F.R. §1.136(a) for the total number of months checked below:

<input type="checkbox"/>	Extension for response filed within the first month:	\$110.00	\$0.00
<input type="checkbox"/>	Extension for response filed within the second month:	\$400.00	\$0.00
<input type="checkbox"/>	Extension for response filed within the third month:	\$920.00	\$0.00
<input type="checkbox"/>	Extension for response filed within the fourth month:	\$1,440.00	\$0.00
<input type="checkbox"/>	Extension for response filed within the fifth month:	\$1,960.00	\$0.00
EXTENSION FEE TOTAL:			\$0.00
CLAIMS AND EXTENSION FEE TOTAL:			\$0.00
<input type="checkbox"/>	Small Entity Fees Apply (subtract ½ of above):		\$0.00
TOTAL FEE:			\$0.00

- ☐ Please charge Deposit Account No. 06-1447 in the amount of \$0.00. A duplicate copy of this transmittal is enclosed.
- ☐ A check in the amount of \$0.00 is enclosed.
- ☒ The Commissioner is hereby authorized to charge any additional fees which may be required regarding this application under 37 C.F.R. §§ 1.16-1.17, or credit any overpayment, to Deposit Account No. 06-1447. Should no proper payment be enclosed herewith, as by a check being in the wrong amount, unsigned, post-dated, otherwise improper or informal or even entirely missing, the Commissioner is authorized to charge the unpaid amount to Deposit Account No. 06-1447.

Please direct all correspondence to the undersigned attorney or agent at the address indicated below.

Respectfully submitted,

Date 12-24-02

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By Joseph N. Ziebert

Joseph N. Ziebert
Attorney for Applicant
Registration No. 35,421



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Josef N Ziehl
(Printed Name)
Josef N Ziehl
(Signature)
12-24-02
(Date of Deposit)

AMENDMENT

Commissioner for Patents
Box AF
Washington, D.C. 20231

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TECHNOLOGY CENTER 2800

Sir:

This communication is responsive to the Office Action dated October 24, 2002, concerning the above-referenced patent application.

Please amend the application as follows:

IN THE CLAIMS:

In accordance with 37 C.F.R. § 1.121, please substitute for original claim 11, the following rewritten versions of the same claims, as amended. The changes are shown explicitly in the attached "Version with Markings to Show Changes Made".

11. (Twice Amended) The method of claim 1, further comprising:
providing a second amorphous semiconductor material above the amorphous semiconductor material including germanium after the laser annealing step;
performing another laser annealing step to form a second single crystalline semiconductor layer from the second amorphous semiconductor material; and